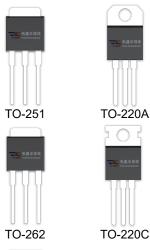


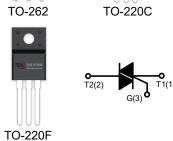
## **DESCRIPTION:**

The BT137-600F SCR series with the parallel resistor between Gate and Cathode are especially recommended for use on straight hair, igniter, anion generator, etc.



### **MAIN FEATURES**

Symbol	Value	Unit
I <sub>T(RMS)</sub>	8	А
V <sub>DRM</sub> /V <sub>RRM</sub>	600 and 800	V



### **ABSOLUTE MAXIMUM RATINGS**

Parameter		Symbol	Value	Unit
Storage junction temperature range		T <sub>stg</sub>	-40-150	$^{\circ}$
Operating junction temperature range		Tj	-40-125	$^{\circ}$
Repetitive peak off-state voltage(T <sub>j</sub> =25℃)		V <sub>DRM</sub>	600/800	V
Repetitive peak reverse voltage(T <sub>j</sub> =25℃)		V <sub>RRM</sub>	600/800	V
RMS on-state current	TO-251/ TO-220A(Non-Ins)/ TO-220C(Tc=95°C) TO-262/ TO-220A(Ins)/ TO-220F(Ins) (Tc=85°C)	I <sub>T(RMS)</sub>	8	A
Non repetitive surge peak on-state current (full cycle, F=50Hz)		Ітѕм	65	Α
I <sup>2</sup> t value for fusing (tp=10ms)		l <sup>2</sup> t	21	A <sup>2</sup> s
Peak gate current		I <sub>GM</sub>	2	Α



Critical rate of rise of on-state current(I <sub>G</sub> =2×I <sub>GT</sub> )	I - II -III	dI/dt	50	A/µs
	IV		10	
Average gate power dissipation	P <sub>G(AV)</sub>	0.5	W	
Peak gate power	P <sub>GM</sub>	5	W	

# **ELECTRICAL CHARACTERISTICS** (T<sub>j</sub>=25°C unless otherwise specified)

Symbol	Test Condition	Quadrant		Value			l lmi4	
				D	Е	F	G	Unit
l <sub>GT</sub>	V <sub>D</sub> =12V R <sub>L</sub> =30Ω	I - II -III	MAX	5	10	25	50	mA
		IV		10	25	70	100	
V <sub>G</sub> T		ALL	MAX	1.3				V
V <sub>GD</sub>	$V_D=V_{DRM}T_j=125$ °C RL=3.3KΩ	ALL	MIN	0.2			V	
IL	Ig=1.2Igт	I -III	MAX	10	20	50	70	mA
		II -IV		20	30	70	100	
Ін	I <sub>T</sub> =100mA		MAX	10	15	40	60	mA
dV/dt	V <sub>D</sub> =2/3V <sub>DRM</sub> Gate Open T <sub>j</sub> =125℃		MIN	20	50	50	200	V/µs

## **STATIC CHARACTERISTICS**

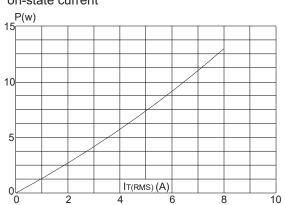
Symbol	Parameter		Value(MAX)	Unit
V <sub>TM</sub>	I <sub>тм</sub> =10A tp=380µs	T <sub>j</sub> =25℃	1.6	V
IDRM	VD=VDRM VR=VRRM	T <sub>j</sub> =25℃	5	μA
IRRM		T <sub>j</sub> =125℃	1	mA

## **THERMAL RESISTANCES**

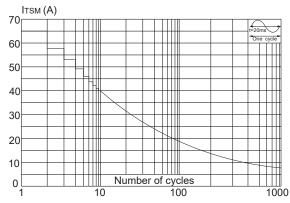
Symbol	Paran	Value	Unit	
R <sub>th(j-c)</sub> junction		TO-251	2.1	- ℃/W
		TO-220A(Non-Ins)/ TO-220C	1.8	
	junction to case(AC)	TO-220A(Ins)/ TO-220F(Ins)	2.9	
		TO-262	3.1	



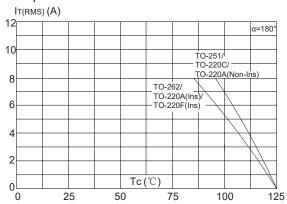
**FIG.1:** Maximum power dissipation versus RMS on-state current



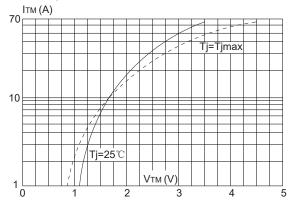
**FIG.3:** Surge peak on-state current versus number of cycles



**FIG.2:** RMS on-state current versus case temperature

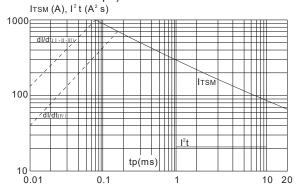


**FIG.4:** On-state characteristics (maximum values)

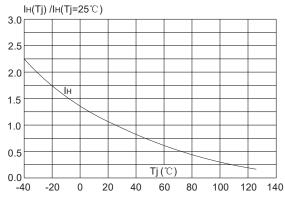




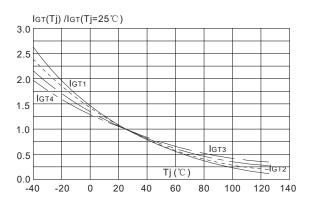
**FIG.5:** Non-repetitive surge peak on-state current for a sinusoidal pulse with width tp<20ms, and corresponging value of  $I^2t$  (  $I - II - III : dI/dt < 50A/\mu s$ ;  $IV : dI/dt < 10A/\mu s$ )



**FIG.7:** Relative variations of holding current versus junction temperature



**FIG.6:** Relative variations of gate trigger current versus junction temperature



**FIG.8:** Relative variations of latching current versus junction temperature

